

ES5JGR

5.0AMPS. SUPER FAST SURFACE MOUNT RECTIFIER

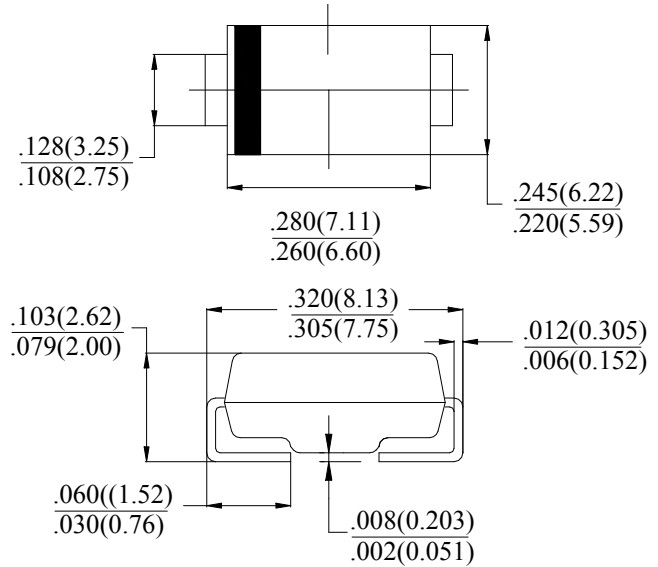
FEATURE

- . High current capability
- . Low forward voltage drop
- . Low power loss, high efficiency
- . High surge capability
- . High temperature soldering guaranteed
260°C/10 seconds at terminals.
- . Superfast recovery time for high efficiency
- . For surface mounted application.
- . Easy pick and place.

MECHANICAL DATA

- . Case: Molded plastic
- . Epoxy: UL94V-0 rate flame retardant
- . Lead: MIL-STD- 202E, Method 208 guaranteed
- . Polarity:Color band denotes cathode end
- . Mounting position: Any

SMC (DO-214AB)



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	SYM BOL	ES5JGR	units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	600	V
Maximum RMS Voltage	V_{RMS}	420	V
Maximum DC blocking Voltage	V_{DC}	600	V
Maximum Average Forward Rectified Current at $T_L = 90^\circ\text{C}$	$I_{F(AV)}$	5.0	A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	120.0	A
Maximum Forward Voltage at 5.0A DC	V_F	1.7	V
Maximum DC Reverse Current @ $T_A = 25^\circ\text{C}$ at rated DC blocking voltage @ $T_A = 125^\circ\text{C}$	I_R	5.0 500.0	μA
Maximum Reverse Recovery Time (Note 1)	t_{rr}	35	nS
Typical Junction Capacitance (Note 2)	C_J	30	pF
Typical Thermal Resistance (Note 3)	$R_{(JA)}$	55	$^\circ\text{C}/\text{W}$
Storage Temperature	T_{STG}	-55 to +150	$^\circ\text{C}$
Operation Junction Temperature	T_J	-55 to +150	$^\circ\text{C}$

Note:

1. Reverse Recovery test Condition: $I_f=0.5\text{A}, I_R=1.0\text{A}, I_{RR}=0.25\text{A}$
2. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc
3. P.C.B.Mounted on $0.6 \times 0.6'' (15.0 \times 15.0\text{mm}) [0.013\text{mm thick}]$ Copper Pad Area.

RATING AND CHARACTERISTIC CURVES (ES5JGR)

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

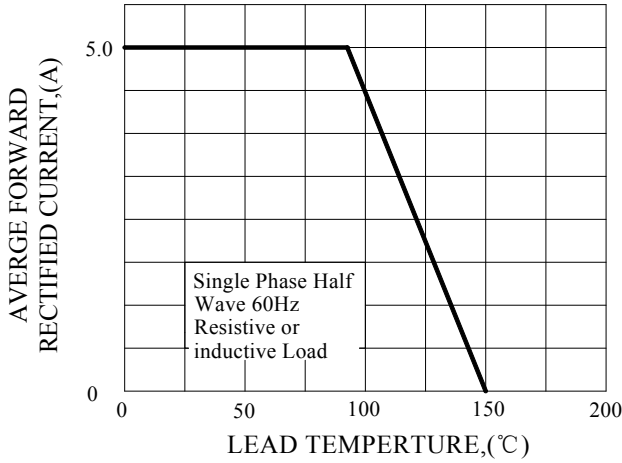


FIG.2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

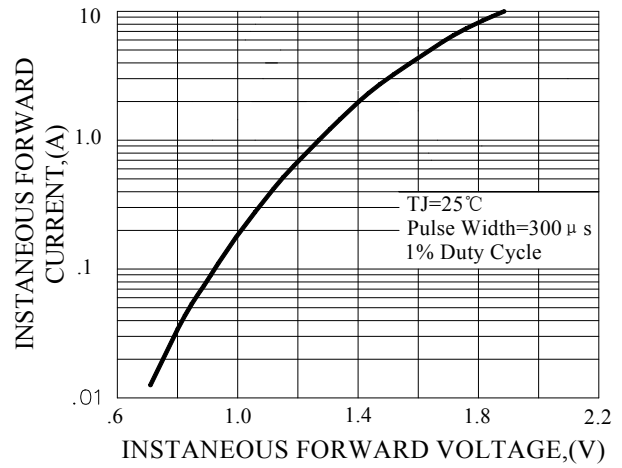


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

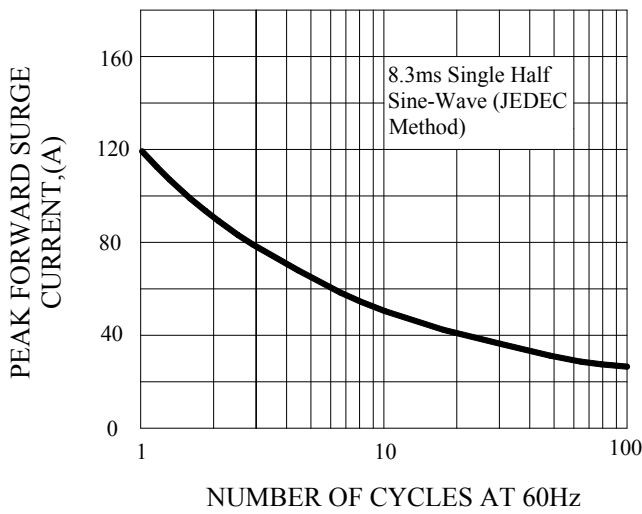


FIG.4-TYPICAL REVERSE CHARACTERISTICS

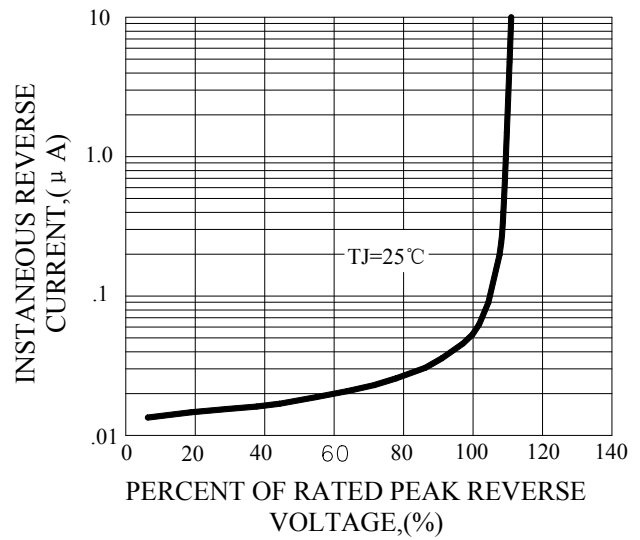
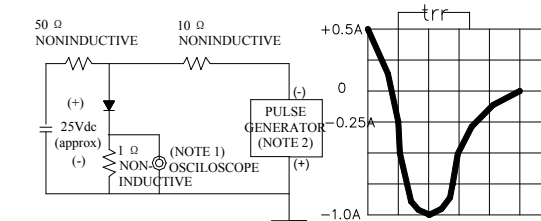
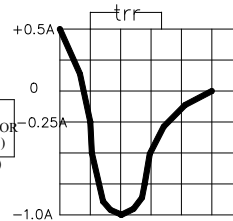


FIG.5-TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC

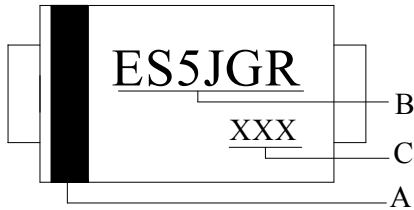


NOTES:1. Rise Time=7ns max, Input Impedance= 1 megohm,22pF.
2. Rise Time=10ns max, Source Impedance= 50 ohms.



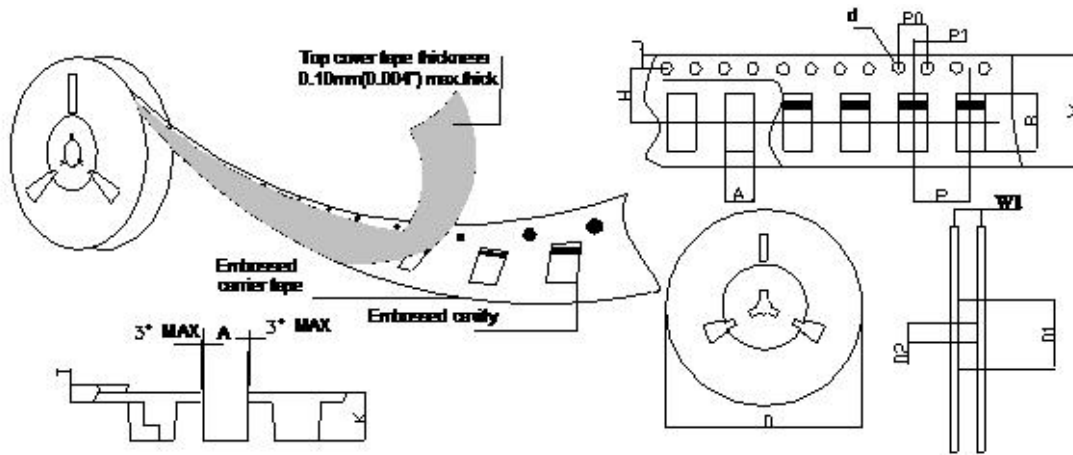
Marking and packaging illustration

1、Marking



SYMBOL	Explanation
A	Color Band Denotes Cathode
B	Product Name
C	Date code

2、Packaging



SPECIFICATIONS mm(inch)		PACKAGE	SPECIFICATIONS mm(inch)		PACKAGE
ITEM	SYM BOL	DO-214AB	ITEM	SYM BOL	DO-214AB
Carrier width	A	6.15(0.242)Max	Carrier depth	K	2.54(0.100)Typ
Carrier length	B	8.41(0.331)Max	Punch hole pitch	P	8.00(0.315)Typ
Sprocket hole	d	ø1.55(0.061)Typ	Sprocket hole pitch	P0	4.00(0.157)Typ
Reel outer diameter	D	330.0(13.0)Typ	Embossment center	P1	2.00(0.079)Typ
Reel inner diameter	D1	74.0(2.913)Min	Overall tape thickness	T	0.25(0.010)Typ
Feed hole diameter	D2	13.0(0.512)Typ	Tape width	W	16.0(0.430)Typ
Sprocket hole position	J	1.75(0.069)Typ	Reel width	W1	16.5(0.650)Min
Punch hole position	H	7.50(0.295)Typ			